

1-Line, Bi-directional, Transient Voltage Supperssor

Description

PESDU0711P0 is a bi-directional TVS (Transient Voltage Suppressor). It has been specifically designed to protect sensitive electronic components which are connected to low speed data lines and control lines from over-stress caused by ESD (Electrostatic Discharge) and Lightning . PESDU0711P0 may be used to provide ESD protection up to $\pm 30 \text{KV}$ (air and contact discharge) according to IEC61000-4-2, and withstand peak pulse current up to $6A(8/20\mu\text{s})$ according to IEC61000-4-5 . PESDU0711P0 is available in DFN0603-2 package. Standard products are Pb-free and Halogen-free.

Features

- Operating voltage: 7V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - —IEC 61000-4-2 (ESD) immunity test

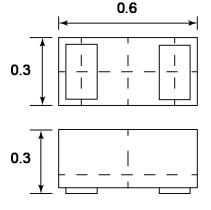
Air discharge: ±30kV

Contact discharge: ±30kV

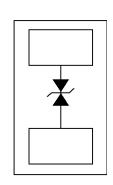
—IEC61000-4-5 (Lightning) 6A (8/20μs)

RoHS Compliant

Dimensions and Pin Configuration







Circuit and Pin Schematic

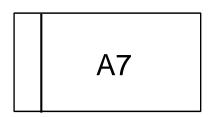
Mechanical Characteristics

- Package: DFN0603-2 (0.6×0.3×0.3mm)
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 1 per J-STD-020
- Marking Information: See Below

Applications

- Cellular Handsets
- CC Line Protection
- Microphone Line Protection
- GPIO Protection

Marking Information



A7 = Device Marking Code

Ordering Information

Part Number	Shipping	Reel Size
PESDU0711P0	10000/Tape & Reel	7 inch



Absolute Maximum Ratings (TA=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	P _{PK}	84	W	
Peak Pulse Current (8/20µs)	IPP	6	А	
ESD per IEC 61000-4-2 (Air)	V	±30	137	
ESD per IEC 61000-4-2 (Contact)	V _{ESD}	±30	kV	
Lead temperature	TL	260	°C	
Operating Temperature Range	Тор	-40 ~ + 85	°C	
Storage Temperature Range	T _{STG}	−55 ~ + 150	°C	

Electrical Characteristics (TA=25°C unless otherwise specified)

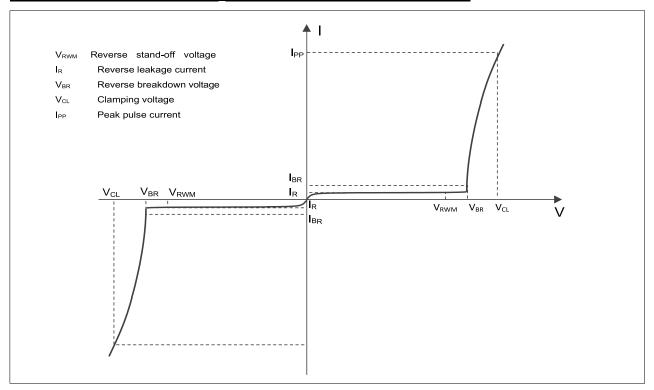
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			7	V	
Breakdown Voltage	V_{BR}	7.2	8		V	$I_T = 1mA$
Reverse Leakage Current	I _R			0.1	μA	V _{RWM} =7V
Clamping voltage ¹⁾	V _{CL}		9.0		V	$I_{PP} = 16A, t_p = 100ns$
Dynamic resistance ¹⁾	R _{DYN}		0.27		Ω	
Clamping voltage ²⁾	V _{CL}		9.0		V	V _{ESD} = 8kV
Clamping Voltage ³⁾	Vc			11	V	I _{PP} = 1A(8/20μs pulse)
Clamping Voltage ³⁾	Vc			14	V	I _{PP} = 6A(8/20µs pulse)
Junction Capacitance	CJ		15	21	pF	$V_R = 0V$, $f = 1MHz$

Notes:

- 1) TLP parameter: $Z_0 = 50\Omega$, tp = 100ns, tr = 2ns, averaging window from 60ns to 80ns. RDYN is calculated from 4A to 16A.
- 2) Contact discharge mode, according to IEC61000-4-2.
- 3) Non-repetitive current pulse, according to IEC61000-4-5.



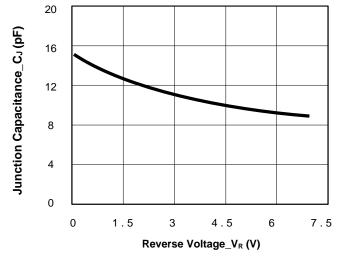
Electrical characteristics (TA = 25°C, unless otherwise noted)



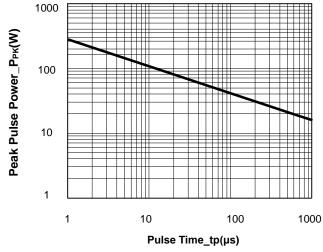
Definitions of electrical characteristics



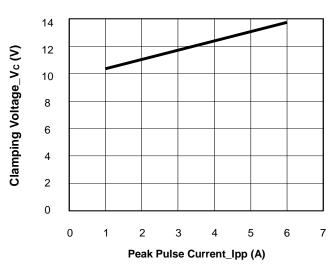
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



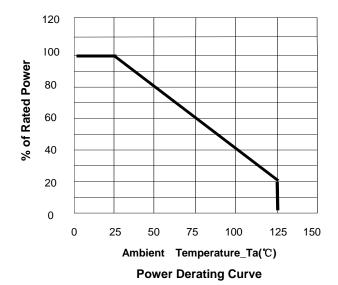
Junction Capacitance vs. Reverse Voltage

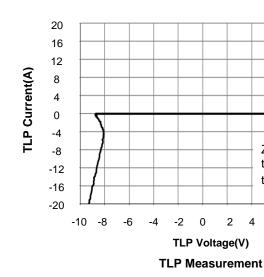


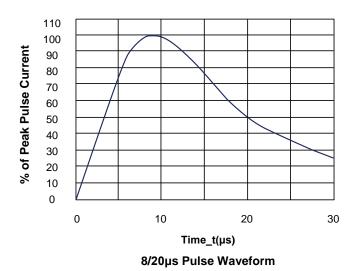
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current







Z₀= 50Ω

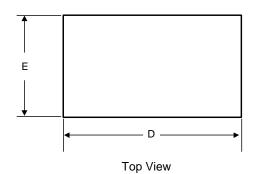
t₀= 100ns

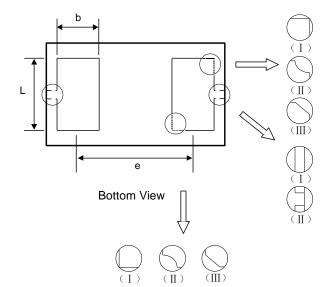
t = 2ns

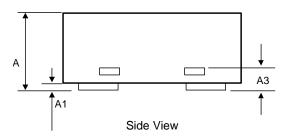
6 8 10



DFN0603-2 Package Outline Drawing

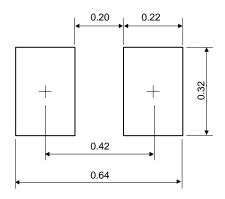






	Dimensions in Millimeters			
Symbol	Min.	Тур.	Max.	
Α	0.230	0.300	0.350	
A1	0.000	-	0.050	
А3		0.102REF.		
D	0.550	0.600	0.670	
E	0.250	0.300	0.370	
b	0.160	0.190	0.230	
L	0.215	0.245	0.275	
е		0.360 BSC		

Recommended PCB Layout (Unit: mm)



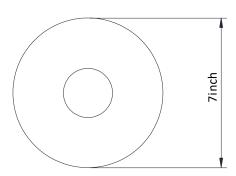
Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

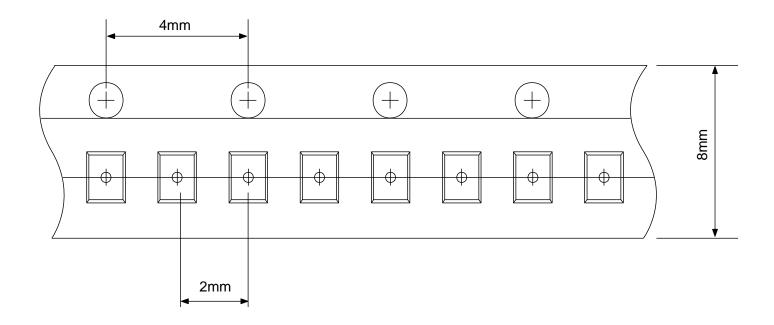


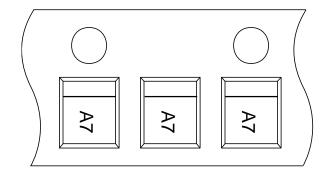
TAPE AND REEL INFORMATION

Reel Dimensions



Tape Dimensions







User Direction of Feed



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